## NSN 5961-01-055-9524

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-055-9524 **Inclosure Material:** Ceramic and glass **Overall Length:** 0.265 inches **Terminal Length:** Between 0.250 inches and 0.350 inches **Overall Height:** 0.080 inches **Overall Width:** 0.155 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -80.0 collector to emitter voltage/static/base open all transistor and -5.0 emitter to base voltage, static, collector open all transistor and -80.0 collector to base voltage/static/emitter open all transistor **Current Rating Per Characteristic:** -600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization:

Yes - demil/mli

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